# **HEF4021B**

# 8-bit static shift register Rev. 9 — 30 August 2013

**Product data sheet** 

#### 1. **General description**

The HEF4021B is an 8-bit static shift register (parallel-to-serial converter) with a synchronous serial data input (DS), a clock input (CP), an asynchronous active HIGH parallel load input (PL), eight asynchronous parallel data inputs (D0 to D7) and buffered parallel outputs from the last three stages (Q5 to Q7).

Each register stage is a D-type master-slave flip-flop with a set direct (SD) and clear direct (CD) input. Information on D0 to D7 is asynchronously loaded into the register while PL is HIGH, independent of CP and DS. When PL is LOW, data on DS is shifted into the first register position and all the data in the register is shifted one position to the right on the LOW-to-HIGH transition of CP. Schmitt trigger action makes the clock input highly tolerant of slower rise and fall times.

It operates over a recommended  $V_{DD}$  power supply range of 3 V to 15 V referenced to  $V_{SS}$ (usually ground). Unused inputs must be connected to V<sub>DD</sub>, V<sub>SS</sub>, or another input.

#### Features and benefits 2.

- Tolerant of slower rise and fall times
- Fully static operation
- 5 V, 10 V, and 15 V parametric ratings
- Standardized symmetrical output characteristics
- Specified from -40 °C to +125 °C
- Complies with JEDEC standard JESD 13-B

#### 3. Ordering information

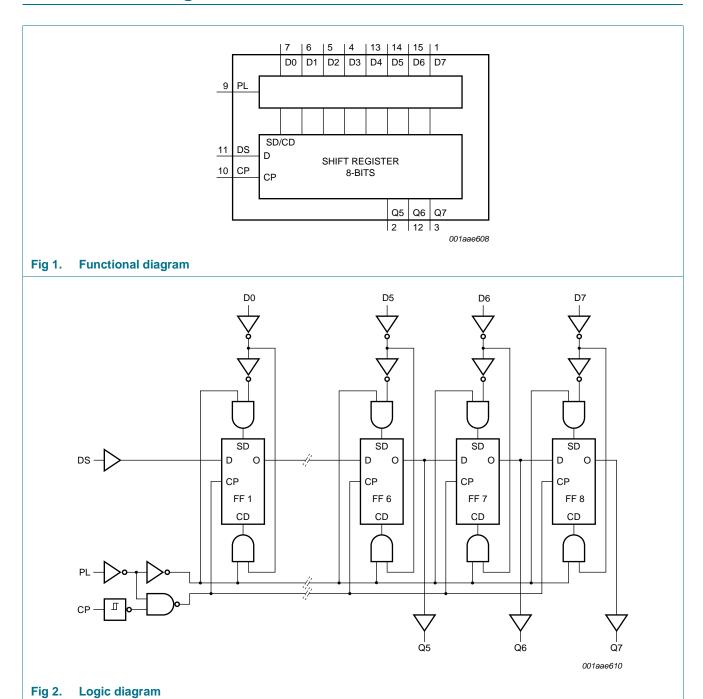
**Ordering information** Table 1.

All types operate from -40 °C to +125 °C.

Type number	Package		Version
	Name	Description	
HEF4021BP	DIP16	plastic dual in-line package; 16 leads (300 mil)	SOT38-4
HEF4021BT	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1
HEF4021BTT	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1

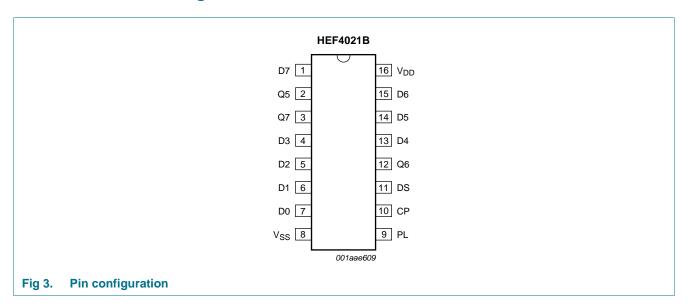


# 4. Functional diagram



# 5. Pinning information

### 5.1 Pinning



# 5.2 Pin description

Table 2. Pin description

Symbol Pin Description Q5 to Q7 2, 12, 3 buffered parallel output from the last three stages	
, , ,	
D0 to D7	
D0 to D7 7, 6, 5, 4, 13, 14,15, 1 parallel data input	
V <sub>SS</sub> 8 ground supply voltage	
PL 9 parallel load input	
CP 10 clock input (LOW-to-HIGH edge-triggered)	
DS 11 serial data input	
V <sub>DD</sub> 16 supply voltage	

# 6. Functional description

Table 3. Function table[1]

Number of clock	Inputs			Outputs			
transitions	СР	DS	PL	Q5	Q6	Q7	
Serial operation							
1	$\uparrow$	data 1	L	X	X	Χ	
2	<b>↑</b>	data 2	L	Χ	Χ	X	
3	<b>↑</b>	data 3	L	Χ	Χ	Χ	
6	<b>↑</b>	X	L	data 1	Χ	Χ	
7	$\uparrow$	X	L	data 2	data 1	Χ	

Table 3. Function table [1] ... continued

Number of clock	Inputs			Outputs		
transitions	СР	DS	PL	Q5	Q6	Q7
8	$\uparrow$	X	L	data 3	data 2	data 1
	<b>\</b>	Χ	L	no change	no change	no change
Parallel operation						
	Χ	Χ	Н	D5	D6	D7

<sup>[1]</sup> H = HIGH voltage level; L = LOW voltage level; X = don't care;

# 7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{DD}$	supply voltage		-0.5	+18	V
I <sub>IK</sub>	input clamping current	$V_I < -0.5 \text{ V or } V_I > V_{DD} + 0.5 \text{ V}$	-	±10	mA
$V_{I}$	input voltage		-0.5	$V_{DD} + 0.5$	V
I <sub>OK</sub>	output clamping current	$V_O < -0.5 \text{ V or } V_O > V_{DD} + 0.5 \text{ V}$	-	±10	mA
I <sub>I/O</sub>	input/output current		-	±10	mA
$I_{DD}$	supply current		-	50	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
T <sub>amb</sub>	ambient temperature		-40	+125	°C
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> –40 °C to +125 °C			
		DIP16 package	<u>[1]</u> _	750	mW
		SO16 and TSSOP16 package	[2]	500	mW
Р	power dissipation	per output	-	100	mW

<sup>[1]</sup> For DIP16 package:  $P_{tot}$  derates linearly with 12 mW/K above 70 °C.

# 8. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{DD}$	supply voltage		3	-	15	V
VI	input voltage		0	-	$V_{DD}$	V
T <sub>amb</sub>	ambient temperature	in free air	-40	-	+125	°C
$\Delta t/\Delta V$	input transition rise and fall rate	$V_{DD} = 5 V$	-	-	3.75	μs/V
		V <sub>DD</sub> = 10 V	-	-	0.5	μs/V
		V <sub>DD</sub> = 15 V	-	-	0.08	μs/V

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 $<sup>\</sup>uparrow$  = LOW to HIGH clock transition;  $\downarrow$  = HIGH to LOW clock transition; data n = data (HIGH or LOW) on the DS input at the n<sup>th</sup>  $\uparrow$  CP transition.

<sup>[2]</sup> For SO16 package:  $P_{tot}$  derates linearly with 8 mW/K above 70 °C. For TSSOP16 package:  $P_{tot}$  derates linearly with 5.5 mW/K above 60 °C.

# 9. Static characteristics

Table 6. Static characteristics

 $V_{SS} = 0$  V;  $V_I = V_{SS}$  or  $V_{DD}$  unless otherwise specified.

Symbol	Parameter	Conditions	$V_{DD}$	T <sub>amb</sub> =	–40 °C	T <sub>amb</sub> =	25 °C	T <sub>amb</sub> =	85 °C	T <sub>amb</sub> =	125 °C	Unit	
				Min	Max	Min	Max	Min	Max	Min	Max		
$V_{IH}$	HIGH-level	$ I_{O}  < 1 \mu A$	5 V	3.5	-	3.5	-	3.5	-	3.5	-	V	
	input voltage		10 V	7.0	-	7.0	-	7.0	-	7.0	-	V	
			15 V	11.0	-	11.0	-	11.0	-	11.0	-	V	
$V_{IL}$	LOW-level	$ I_O  < 1 \mu A$	5 V	-	1.5	-	1.5	-	1.5	-	1.5	V	
	input voltage		10 V	-	3.0	-	3.0	-	3.0	-	3.0	V	
			15 V	-	4.0	-	4.0	-	4.0	-	4.0	V	
$V_{OH}$	HIGH-level	$ I_O  < 1 \mu A$	5 V	4.95	-	4.95	-	4.95	-	4.95	-	V	
	output voltage		10 V	9.95	-	9.95	-	9.95	-	9.95	-	V	
	voltage		15 V	14.95	-	14.95	-	14.95	-	14.95	-	V	
$V_{OL}$	LOW-level		$ I_{O}  < 1 \mu A$	5 V	-	0.05	-	0.05	-	0.05	-	0.05	V
	output voltage		10 V	-	0.05	-	0.05	-	0.05	-	0.05	V	
	voltage		15 V	-	0.05	-	0.05	-	0.05	-	0.05	V	
I <sub>OH</sub>	HIGH-level	$V_0 = 2.5 \text{ V}$	5 V	-	-1.7	-	-1.4	-	-1.1	-	-1.1	mA	
	output current	$V_0 = 4.6 \text{ V}$	5 V	-	-0.64	-	-0.5	-	-0.36	-	-0.36	mA	
		$V_0 = 9.5 V$	10 V	-	-1.6	-	-1.3	-	-0.9	-	-0.9	mA	
		$V_0 = 13.5 \text{ V}$	15 V	-	-4.2	-	-3.4	-	-2.4	-	-2.4	mA	
$I_{OL}$	LOW-level	$V_O = 0.4 V$	5 V	0.64	-	0.5	-	0.36	-	0.36	-	mA	
	output current	$V_0 = 0.5 \ V$	10 V	1.6	-	1.3	-	0.9	-	0.9	-	mΑ	
		$V_0 = 1.5 \text{ V}$	15 V	4.2	-	3.4	-	2.4	-	2.4	-	mA	
II	input leakage current	$V_{DD} = 15 \text{ V}$	15 V	-	±0.1	-	±0.1	-	±1.0	-	±1.0	μΑ	
$I_{DD}$	supply	I <sub>O</sub> = 0 A	5 V	-	5	-	5	-	150	-	150	μΑ	
	current		10 V	-	10	-	10	-	300	-	300	μΑ	
			15 V	-	20	-	20	-	600	-	600	μΑ	
C <sub>I</sub>	input capacitance		-	-	-	-	7.5	-	-	-	-	pF	

# 10. Dynamic characteristics

Table 7. Dynamic characteristics

 $V_{SS} = 0 \text{ V; } T_{amb} = 25 \text{ °C; for test circuit see } Figure 7; unless otherwise specified.}$ 

Symbol	Parameter	Conditions	$V_{DD}$	Extrapolation formula	Min	Тур	Max	Unit
t <sub>PHL</sub> HIGH to LOW propagation delay		CP to Qn	5 V	11 98 ns + (0.55 ns/pF)C <sub>L</sub>	-	125	250	ns
	see <u>Figure 4</u>	10 V	44 ns + (0.23 ns/pF)C <sub>L</sub>	-	55	110	ns	
			15 V	32 ns + (0.16 ns/pF)C <sub>L</sub>	-	40	80	ns
		PL to Qn	5 V	93 ns + (0.55 ns/pF)C <sub>L</sub>	-	120	240	ns
		see <u>Figure 4</u>	10 V	44 ns + (0.23 ns/pF)C <sub>L</sub>	-	55	110	ns
			15 V	32 ns + $(0.16 \text{ ns/pF})C_L$	-	40	80	ns

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 Table 7.
 Dynamic characteristics ...continued

 $V_{SS} = 0 \text{ V; } T_{amb} = 25 \text{ °C; for test circuit see } \underline{Figure 7}; unless otherwise specified.$ 

Symbol	Parameter	Conditions	$V_{DD}$	Extrapolation formula	Min	Тур	Max	Unit
t <sub>PLH</sub>	LOW to HIGH	CP to Qn	5 V	11 88 ns + (0.55 ns/pF)C <sub>L</sub>	-	115	230	ns
	propagation delay	see Figure 4	10 V	39 ns + (0.23 ns/pF)C <sub>L</sub>	-	50	100	ns
			15 V	32 ns + (0.16 ns/pF)C <sub>L</sub>	-	40	80	ns
		PL to Qn	5 V	78 ns + (0.55 ns/pF)C <sub>L</sub>	-	105	210	ns
		see Figure 4	10 V	39 ns + (0.23 ns/pF)C <sub>L</sub>	-	50	100	ns
			15 V	32 ns + (0.16 ns/pF)C <sub>L</sub>	-	40	80	ns
t <sub>t</sub>	transition time	Qn; see Figure 4	5 V	10 ns + (1.00 ns/pF)C <sub>L</sub>	-	60	120	ns
			10 V	9 ns + (0.42 ns/pF)C <sub>L</sub>	-	30	60	ns
			15 V	6 ns + (0.28 ns/pF)C <sub>L</sub>	-	20	40	ns
t <sub>su</sub>	set-up time	DS to CP;	5 V		+25	-15	-	ns
		see Figure 5	10 V		+25	-10	-	ns
		15 V		+15	-5	-	ns	
		Dn to PL;	5 V		50	25	-	ns
		see Figure 6	10 V		30	10	-	ns
			15 V		20	5	-	ns
t <sub>h</sub>	h hold time	DS to CP; see Figure 5  Dn to PL; see Figure 6	5 V		40	20	-	ns
			10 V		20	10	-	ns
			15 V		15	8	-	ns
			5 V		+15	-10	-	ns
			10 V		15	0	-	ns
			15 V		15	0	-	ns
$t_{\text{W}}$	pulse width	CP = LOW;	5 V		70	35	-	ns
		minimum width; see Figure 5	10 V		30	15	-	ns
			15 V		24	12	-	ns
		PL = HIGH;	5 V		70	35	- ns - ns - ns - ns - ns - ns	ns
		minimum width; see Figure 6	10 V		30	15		ns
		<u>ga. o                                 </u>	15 V		24	12	-	ns
$t_{rec}$	recovery time	PL input;	5 V		50	10	-	ns
		see <u>Figure 6</u>	10 V		40	5	-	ns
			15 V		35	5	-	ns
$f_{clk(max)}$	maximum clock	CP input;	5 V		6	13	-	MHz
	frequency	see <u>Figure 5</u>	10 V		15	30	-	MHz
			15 V		20	40	-	MHz

<sup>[1]</sup> The typical values of the propagation delay and transition times are calculated from the extrapolation formulas shown (C<sub>L</sub> in pF).

Table 8. Dynamic power dissipation P<sub>D</sub>

 $P_D$  can be calculated from the formulas shown.  $V_{SS} = 0$  V;  $t_r = t_f \le 20$  ns;  $T_{amb} = 25$  °C.

Symbol	Parameter	$V_{DD}$	Typical formula for P <sub>D</sub> (μW)	where:
$P_D$	dynamic power	5 V	$P_D = 900 \times f_i + \Sigma (f_o \times C_L) \times V_{DD}^2$	$f_i$ = input frequency in MHz,
	dissipation	10 V	$P_D = 4300 \times f_i + \Sigma (f_o \times C_L) \times V_{DD}^2$	fo = output frequency in MHz,
		15 V	$P_D = 12000 \times f_i + \Sigma (f_0 \times C_L) \times V_{DD}^2$	$C_L$ = output load capacitance in pF, $V_{DD}$ = supply voltage in V, $\Sigma(f_o \times C_L)$ = sum of the outputs.

### 11. Waveforms

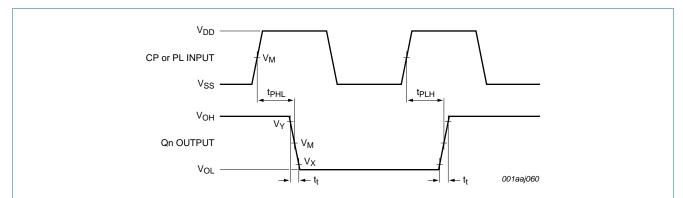


Fig 4. Waveforms showing propagation delays for CP and PL inputs to Qn output and Qn transition times

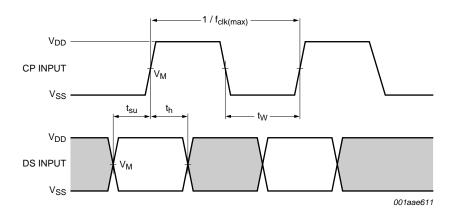


Fig 5. Waveforms showing minimum clock pulse width, set-up time, and hold time for CP and DS.

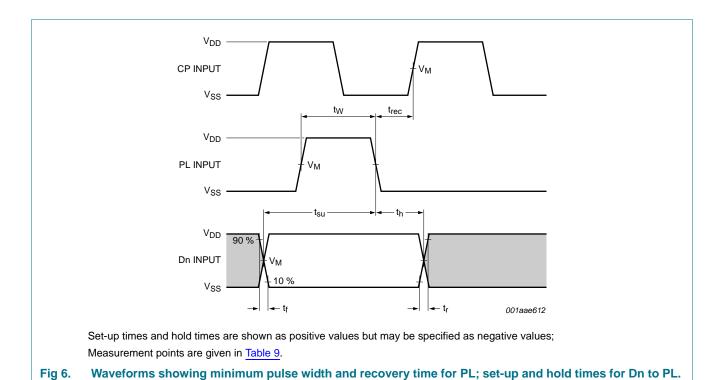
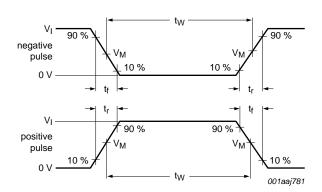
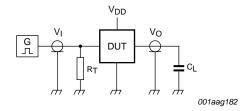


Table 9. Measurement points

Supply voltage	Input	Output		
$V_{DD}$	V <sub>M</sub>	V <sub>M</sub>	V <sub>X</sub>	V <sub>Y</sub>
5 V to 15 V	0.5V <sub>DD</sub>	0.5V <sub>DD</sub>	0.1V <sub>DD</sub>	0.9V <sub>DD</sub>



### a. Input waveform



#### b. Test circuit

Test data is given in Table 10.

Definitions for test circuit:

DUT = Device Under Test.

C<sub>L</sub> = load capacitance including jig and probe capacitance.

 $R_T$  = termination resistance should be equal to the output impedance  $Z_0$  of the pulse generator.

Fig 7. Test circuit for measuring switching times

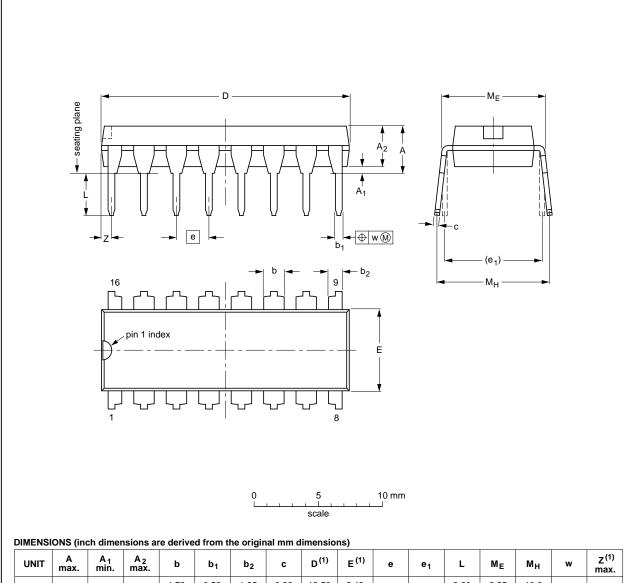
### Table 10. Test data

Supply voltage	Input	Load	
$V_{DD}$	VI	t <sub>r</sub> , t <sub>f</sub>	CL
5 V to 15 V	V <sub>SS</sub> or V <sub>DD</sub>	≤ 20 ns	50 pF

# 12. Package outline

### DIP16: plastic dual in-line package; 16 leads (300 mil)

SOT38-4



UNIT	A max.	A <sub>1</sub> min.	A <sub>2</sub> max.	b	b <sub>1</sub>	b <sub>2</sub>	С	D <sup>(1)</sup>	E <sup>(1)</sup>	е	e <sub>1</sub>	L	ME	Мн	w	Z <sup>(1)</sup> max.
mm	4.2	0.51	3.2	1.73 1.30	0.53 0.38	1.25 0.85	0.36 0.23	19.50 18.55	6.48 6.20	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	0.76
inches	0.17	0.02	0.13	0.068 0.051	0.021 0.015	0.049 0.033	0.014 0.009	0.77 0.73	0.26 0.24	0.1	0.3	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.03

#### Note

1. Plastic or metal protrusions of 0.25 mm (0.01 inch) maximum per side are not included.

OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE
SOT38-4					<del>95-01-14</del> 03-02-13

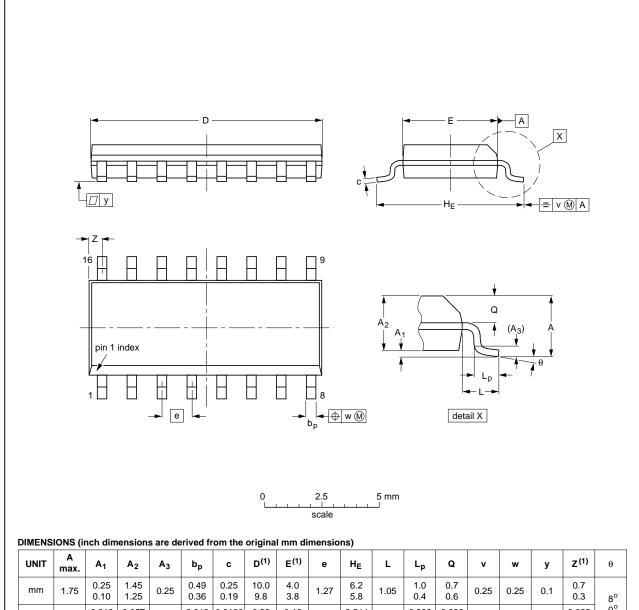
Fig 8. Package outline SOT38-4 (DIP16)

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### SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1



UNIT	A max.	A <sub>1</sub>	A <sub>2</sub>	A <sub>3</sub>	bp	С	D <sup>(1)</sup>	E <sup>(1)</sup>	е	HE	L	Lp	ø	v	w	у	Z <sup>(1)</sup>	θ
mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	10.0 9.8	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8°
inches	0.069	0.010 0.004	0.057 0.049	0.01	l	0.0100 0.0075	0.39 0.38	0.16 0.15	0.05	0.244 0.228	0.041	0.039 0.016		0.01	0.01	0.004	0.028 0.012	0°

#### Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT109-1	076E07	MS-012				<del>99-12-27</del> 03-02-19	

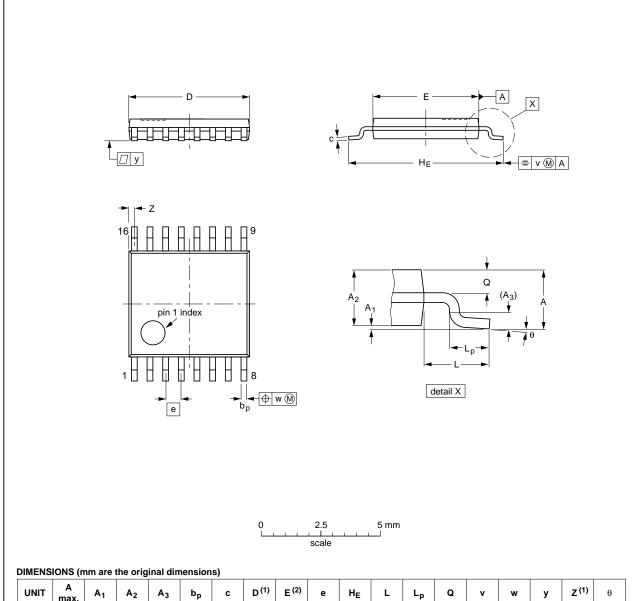
Fig 9. Package outline SOT109-1 (SO16)

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TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm

SOT403-1



UNIT	A max.	A <sub>1</sub>	A <sub>2</sub>	A <sub>3</sub>	bp	С	D <sup>(1)</sup>	E <sup>(2)</sup>	е	HE	L	Lp	Q	v	w	у	Z <sup>(1)</sup>	θ
mm	1.1	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	5.1 4.9	4.5 4.3	0.65	6.6 6.2	1	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.40 0.06	8° 0°

#### Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

VERSION IEC JEDEC JEITA PROJECTION 99-12-1	OUTLINE		REFER	EUROPEAN	ISSUE DATE			
SO(403-1)	VERSION	IEC	JEDEC	JEITA		PROJECTION	1330E DATE	
03-02-	SOT403-1		MO-153				<del>99-12-27</del> 03-02-18	

Fig 10. Package outline SOT403-1 (TSSOP16)

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# 13. Revision history

### Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
HEF4021B v.9	20130830	Product data sheet	-	HEF4021B v.8
Modifications:	<ul> <li>added type</li> </ul>	number HEF4021BTT.		
HEF4021B v.8	20111118	Product data sheet	-	HEF4021B v.7
Modifications:	<ul> <li>Legal page:</li> </ul>	s updated.		
	<ul> <li>Changes in</li> </ul>	"General description" and "	Features and benefits".	
	<ul> <li>Section "Ap</li> </ul>	plications" removed.		
HEF4021B v.7	20111010	Product data sheet	-	HEF4021B v.6
HEF4021B v.6	20091127	Product data sheet	-	HEF4021B v.5
HEF4021B v.5	20090707	Product data sheet	-	HEF4021B v.4
HEF4021B v.4	20081110	Product data sheet	-	HEF4021B_CNV v.3
HEF4021B_CNV v.3	19950101	Product specification	-	HEF4021B_CNV v.2
HEF4021B_CNV v.2	19950101	Product specification	-	-

## 14. Legal information

### 14.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <a href="http://www.nxp.com">http://www.nxp.com</a>.

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